

## SGM8544C 1.1MHz, 46µA, Rail-to-Rail I/O CMOS Operational Amplifier

#### GENERAL DESCRIPTION

The SGM8544C is a quad, low cost, voltage feedback amplifier. The device can operate from 2.1V to 5.5V single supply, while consuming only 46µA quiescent current per amplifier. It provides rail-to-rail input with a wide input common mode voltage range and rail-to-rail output voltage swing. This feature makes SGM8544C appropriate for buffering ASIC.

The SGM8544C offers a gain-bandwidth product of 1.1MHz and an ultra-low input bias current of 0.5pA. It is well suited for piezoelectric sensors, integrators and photodiode amplifiers.

The SGM8544C is designed into a wide range of applications, such as battery-powered instrumentation, safety monitoring, portable systems, and transducer interface circuits in low power systems.

The SGM8544C is available in a Green TSSOP-14 package. It is specified over the extended industrial temperature range (-40°C to +125°C).

#### **FEATURES**

- Low Cost
- Input Offset Voltage: 0.8mV (TYP)
  Ultra-Low Input Bias Current: 0.5pA
- Unity-Gain Stable
- Gain-Bandwidth Product: 1.1MHz
- Rail-to-Rail Input and Output
- Supply Voltage Range: 2.1V to 5.5V
- Input Voltage Range:
  - -0.1V to 5.6V with  $V_S = 5.5V$
- Low Supply Current: 46µA/Amplifier
- -40°C to +125°C Operating Temperature Range
- Available in a Green TSSOP-14 Package

#### **APPLICATIONS**

**ASIC Input or Output Amplifiers** 

Piezoelectric Transducer Amplifiers

**Battery-Powered Equipment** 

Portable Equipment

Sensor Interfaces

**Medical Instrumentation** 

Mobile Communications

**Audio Outputs** 

**Smoke Detectors** 

Notebook PCs

**PCMCIA Cards** 

Mobile Telephones

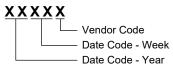


#### PACKAGE/ORDERING INFORMATION

| MODEL   | PACKAGE<br>DESCRIPTION | SPECIFIED<br>TEMPERATURE<br>RANGE | ORDERING<br>NUMBER | PACKAGE<br>MARKING        | PACKING<br>OPTION   |  |
|---------|------------------------|-----------------------------------|--------------------|---------------------------|---------------------|--|
| SGM8544 | C TSSOP-14             | -40°C to +125°C                   | SGM8544CXTS14G/TR  | SGM8544<br>XTS14<br>XXXXX | Tape and Reel, 4000 |  |

#### MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### **ABSOLUTE MAXIMUM RATINGS**

| Supply Voltage, +V <sub>S</sub> to -V <sub>S</sub> | 6V                          |
|--|-----------------------------|
| Input Common Mode Voltage Range                    |                             |
| (-V <sub>S</sub> )                                 | - $0.3V$ to $(+V_S) + 0.3V$ |
| Junction Temperature                               | +150°C                      |
| Storage Temperature Range                          | 65°C to +150°C              |
| Lead Temperature (Soldering, 10s)                  | +260°C                      |
| ESD Susceptibility                                 |                             |
| HBM  | 4000V                       |
| MM   | 400V                        |

#### RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range .....-40°C to +125°C

#### OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

#### **ESD SENSITIVITY CAUTION**

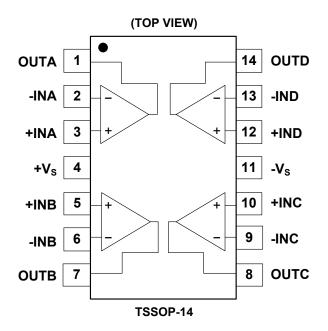
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision

integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

#### **DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

#### PIN CONFIGURATION



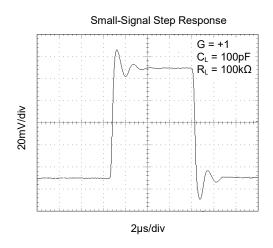
## **ELECTRICAL CHARACTERISTICS**

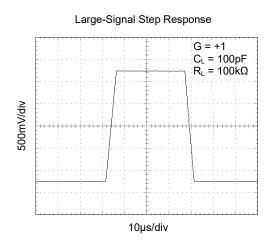
(At  $V_S$  = +5V,  $R_L$  = 100k $\Omega$  connected to  $V_S/2$  and  $V_{OUT}$  =  $V_S/2$ , unless otherwise noted.)

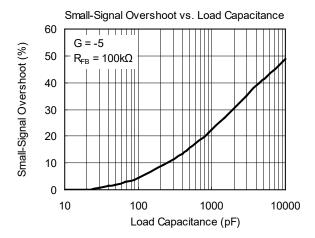
|  |                      |   | SGM8544C     |                          |                    |                    |             |  |
|--|----------------------|---|--------------|--------------------------|--------------------|--------------------|-------------|--|
| DADAMETED                                    | OVMBOL               | CONDITIONS  | TYP          | MIN/MAX OVER TEMPERATURE |                    |                    |             |  |
| PARAMETER                                    | SYMBOL               | CONDITIONS +25°C  |              | +25℃                     | -40°C to<br>+125°C | UNITS              | MIN/<br>MAX |  |
| Input Characteristics                        |                      |   |              |                          |                    |                    |             |  |
| Input Offset Voltage                         | Vos                  | $V_{CM} = V_S/2$  | 0.8          | 3.5                      |                    | mV                 | MAX         |  |
| Input Bias Current                           | Ι <sub>Β</sub>       |   | 0.5          |                          |                    | pА                 | TYP         |  |
| Input Offset Current                         | Ios                  |   | 0.5          |                          |                    | pА                 | TYP         |  |
| Input Common Mode Voltage Range              | $V_{CM}$             | V <sub>S</sub> = 5.5V                                   | -0.1 to +5.6 |                          |                    | V                  | TYP         |  |
| Common Mada Bajastian Batia                  | CMRR                 | $V_S = 5.5V$ , $V_{CM} = -0.1V$ to +4V                  | 87           | 71                       | 69                 | dB                 | MINI        |  |
| Common Mode Rejection Ratio                  | CIVIRR               | V <sub>S</sub> = 5.5V, V <sub>CM</sub> = -0.1V to +5.6V | 80           | 60                       | 56                 | иь                 | MIN         |  |
| Onen Leen Voltage Cein                       | ۸                    | $R_L = 5k\Omega$ , $V_O = +0.1V$ to $+4.9V$             | 98           | 80                       | 73                 | dB M               | MIN         |  |
| Open-Loop Voltage Gain                       | A <sub>OL</sub>      | $R_L = 100k\Omega$ , $V_O = +0.035V$ to +4.965V         | 105          | 85                       | 74                 | иь                 | IVIIIN      |  |
| Input Offset Voltage Drift                   | ΔV <sub>OS</sub> /ΔT |   | 2.7          |                          |                    | μV/°C              | TYP         |  |
| Output Characteristics                       |                      |   |              |                          |                    |                    | •           |  |
|  | $V_{OH}$             | $R_L = 100k\Omega$                                      | 4.997        | 4.980                    | 4.970              | V                  | V MAX       |  |
| Output Vallage Output from Ball              | V <sub>OL</sub>      | $R_L = 100k\Omega$                                      | 5            | 20                       | 30                 | mV                 | MAX         |  |
| Output Voltage Swing from Rail               | V <sub>OH</sub>      | $R_L = 10k\Omega$                                       | 4.992        | 4.970                    | 4.960              |                    |             |  |
|  | V <sub>OL</sub>      | $R_L = 10k\Omega$                                       | 8            | 30                       | 40                 | mV                 | MAX         |  |
| Outrast Comment                              | I <sub>SOURCE</sub>  | D = 400 to 1/ /2  | 85           | 60                       | 45                 | 0                  | MIN         |  |
| Output Current                               | I <sub>SINK</sub>    | $R_L = 10\Omega$ to $V_S/2$                             | 75           | 60                       | 45                 | mA                 |             |  |
| Power Supply                                 |                      |   | •            |                          | 1                  | •                  |             |  |
| 0 " 1/ " 5                                   |                      |   |              | 2.1                      | 2.5                | V                  | MIN         |  |
| Operating Voltage Range                      |                      |   |              | 5.5                      | 5.5                | V                  | MAX         |  |
| Power Supply Rejection Ratio                 | PSRR                 | $V_S = +2.5V$ to +5.5V, $V_{CM} = +0.5V$                | 87           | 70                       | 64                 | dB                 | MIN         |  |
| Quiescent Current/Channel                    | ΙQ                   |   | 46           | 69                       | 89                 | μΑ                 | MAX         |  |
| Dynamic Performance (C <sub>L</sub> = 100pF) |                      |   |              |                          | · ·                | •                  |             |  |
| Gain-Bandwidth Product                       | GBP                  |   | 1.1          |                          |                    | MHz                | TYP         |  |
| Slew Rate                                    | SR                   | G = +1, 2V Output Step                                  | 0.52         |                          |                    | V/µs               | TYP         |  |
| Settling Time to 0.1%                        | ts                   | G = +1, 2V Output Step                                  | 5.3          |                          |                    | μs                 | TYP         |  |
| Overload Recovery Time                       |                      | V <sub>IN</sub> ·Gain = V <sub>S</sub>                  | 2.6          |                          |                    | μs                 | TYP         |  |
| Noise Performance                            |                      | •   |              |                          |                    | •                  | •           |  |
| Maltana Naisa Dan ''                         | _                    | f = 1kHz  | 27           |                          |                    | nV/ <sub>√Hz</sub> | TYP         |  |
| Voltage Noise Density                        | e <sub>n</sub>       | f = 10kHz   | 20           |                          |                    | nV/ <sub>√Hz</sub> | TYP         |  |

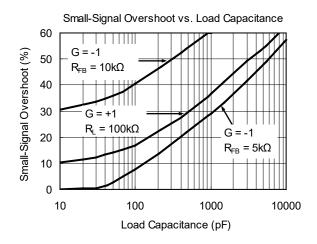
#### TYPICAL PERFORMANCE CHARACTERISTICS

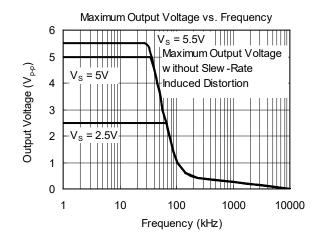
At  $T_A$  = +25°C,  $V_S$  = +5V, and  $R_L$  = 100k $\Omega$  connected to  $V_S/2$ , unless otherwise noted.

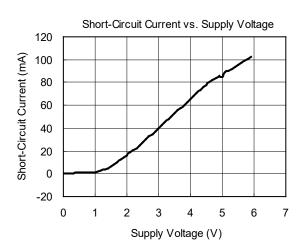






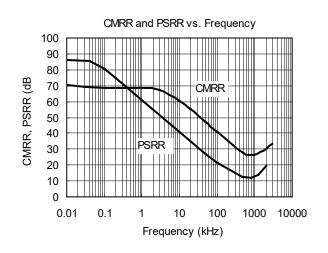


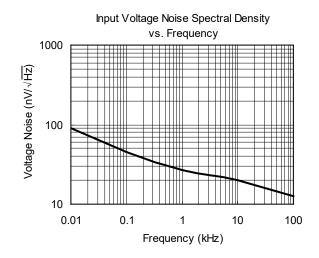


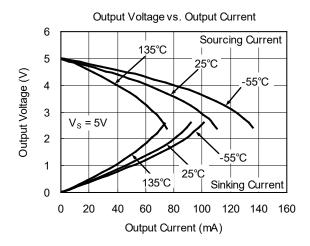


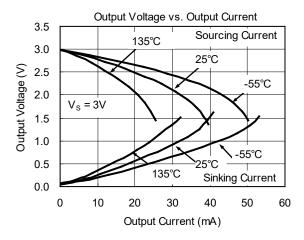
## **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

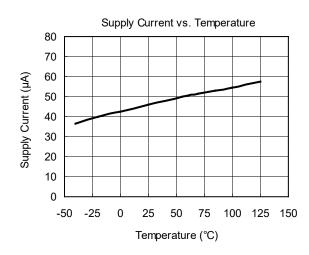
At  $T_A$  = +25°C,  $V_S$  = +5V, and  $R_L$  = 100k $\Omega$  connected to  $V_S/2$ , unless otherwise noted.

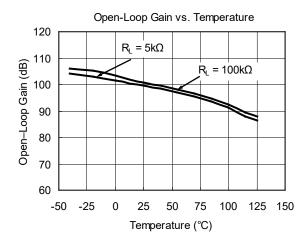






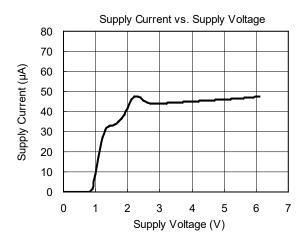


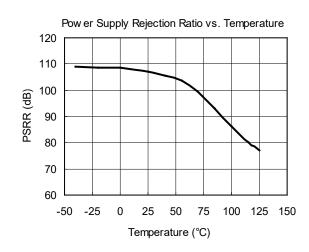


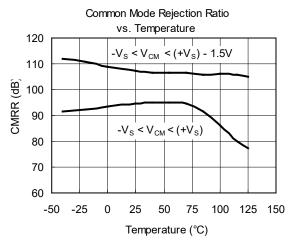


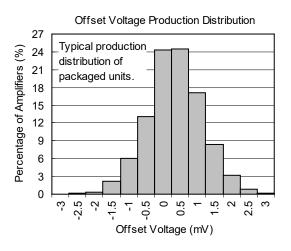
## **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

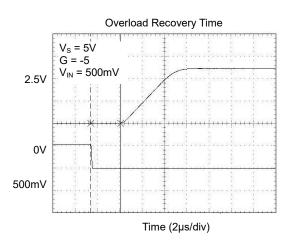
At  $T_A$  = +25°C,  $V_S$  = +5V, and  $R_L$  = 100k $\Omega$  connected to  $V_S/2$ , unless otherwise noted.











#### **APPLICATION INFORMATION**

#### Rail-to-Rail Input

When SGM8544C works at the power supply between 2.1V and 5.5V, the input common mode voltage range is from (-V<sub>S</sub>) - 0.1V to (+V<sub>S</sub>) + 0.1V. In Figure 1, the ESD diodes between the inputs and the power supply rails will clamp the input voltage not to exceed the rails.

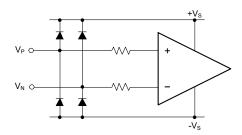


Figure 1. Input Equivalent Circuit

#### Rail-to-Rail Output

The SGM8544C supports rail-to-rail output operation. In single power supply application, for example, when +V<sub>S</sub> = 5V, -V<sub>S</sub> = GND,  $100k\Omega$  load resistor is tied from OUT pin to V<sub>S</sub>/2, the typical output swing range is from 0.005V to 4.997V.

#### **Driving Capacitive Loads**

The SGM8544C is designed for unity-gain stable for capacitive load up to 250pF. If greater capacitive load must be driven in application, the circuit in Figure 2 can be used. In this circuit, the IR drop voltage generated by  $R_{\rm ISO}$  is compensated by feedback loop.

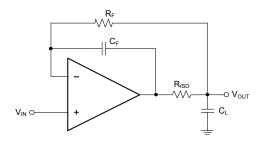


Figure 2. Circuit to Drive Heavy Capacitive Load

#### **Power Supply Decoupling and Layout**

A clean and low noise power supply is very important in amplifier circuit design, besides of input signal noise, the power supply is one of important source of noise to the amplifiers through  $+V_S$  and  $-V_S$  pins. Power supply bypassing is an effective method to clear up the noise at power supply, and the low impedance path to ground of decoupling capacitor will bypass the noise to GND. In application,  $10\mu F$  ceramic capacitor paralleled with  $0.1\mu F$  or  $0.01\mu F$  ceramic capacitor is used in Figure 3. The ceramic capacitors should be placed as close as possible to  $+V_S$  and  $-V_S$  power supply pins.

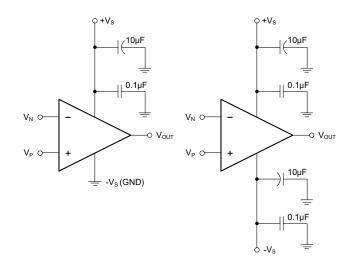


Figure 3. Amplifier Power Supply Bypassing

## **APPLICATION INFORMATION (continued)**

#### **Typical Application Circuits**

#### **Difference Amplifier**

The circuit in Figure 4 is a design example of classical difference amplifier. If  $R_4/R_3 = R_2/R_1$ , then  $V_{OUT} = (V_P - V_N) \times R_2/R_1 + V_{REF}$ .

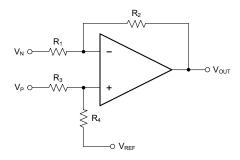


Figure 4. Difference Amplifier

#### **High Input Impedance Difference Amplifier**

The circuit in Figure 5 is a design example of high input impedance difference amplifier, the added amplifiers at the input are used to increase the input impedance and eliminate drawback of low input impedance in Figure 4.

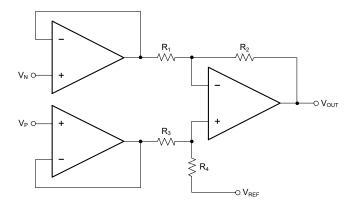


Figure 5. High Input Impedance Difference Amplifier

#### **Active Low-Pass Filter**

The circuit in Figure 6 is a design example of active low-pass filter, the DC gain is equal to  $-R_2/R_1$  and the -3dB corner frequency is equal to  $1/2\pi R_2C$ . In this design, the filter bandwidth must be less than the bandwidth of the amplifier, the resistor values must be selected as low as possible to reduce ringing or oscillation generated by the parasitic parameters in PCB layout.

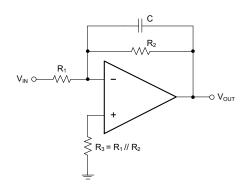


Figure 6. Active Low-Pass Filter

## 1.1MHz, 46µA, Rail-to-Rail I/O CMOS Operational Amplifier

## **SGM8544C**

## **REVISION HISTORY**

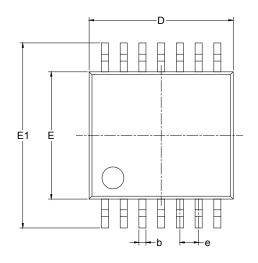
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

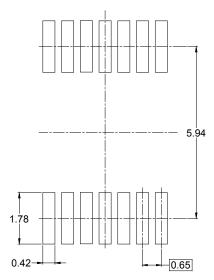
Changes from Original (NOVEMBER 2017) to REV.A

Page

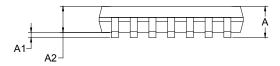


# PACKAGE OUTLINE DIMENSIONS TSSOP-14





RECOMMENDED LAND PATTERN (Unit: mm)

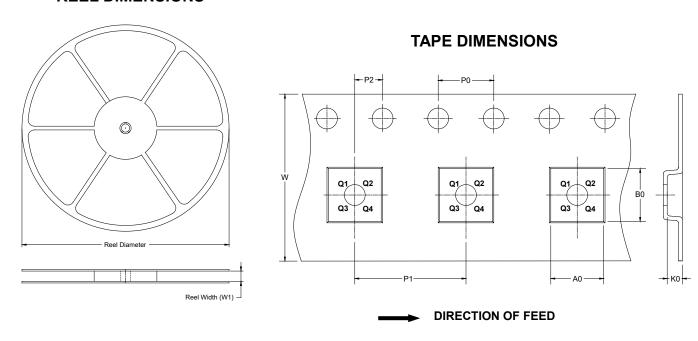




| Symbol | _     | nsions<br>imeters | Dimensions<br>In Inches |       |  |
|--------|-------|-------------------|-------------------------|-------|--|
|        | MIN   | MAX               | MIN                     | MAX   |  |
| А      |       | 1.200             |                         | 0.047 |  |
| A1     | 0.050 | 0.150             | 0.002                   | 0.006 |  |
| A2     | 0.800 | 1.050             | 0.031                   | 0.041 |  |
| b      | 0.190 | 0.300             | 0.007                   | 0.012 |  |
| С      | 0.090 | 0.200             | 0.004                   | 0.008 |  |
| D      | 4.860 | 5.100             | 0.191                   | 0.201 |  |
| Е      | 4.300 | 4.500             | 0.169                   | 0.177 |  |
| E1     | 6.250 | 6.550             | 0.246                   | 0.258 |  |
| е      | 0.650 | 0.650 BSC         |                         | BSC   |  |
| L      | 0.500 | 0.700             | 0.02                    | 0.028 |  |
| Н      | 0.25  | 0.25 TYP          |                         | TYP   |  |
| θ      | 1° 7° |                   | 1°                      | 7°    |  |

## TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**

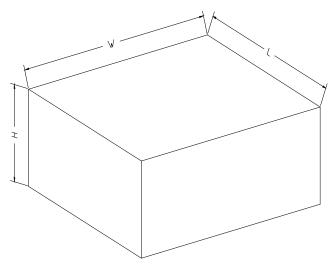


NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF TAPE AND REEL**

| Package Type | Reel<br>Diameter | Reel Width<br>W1<br>(mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P0<br>(mm) | P1<br>(mm) | P2<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|--------------|------------------|--------------------------|------------|------------|------------|------------|------------|------------|-----------|------------------|
| TSSOP-14     | 13"              | 12.4                     | 6.95       | 5.60       | 1.20       | 4.0        | 8.0        | 2.0        | 12.0      | Q1               |

#### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF CARTON BOX**

| Reel Type | Length<br>(mm) | Width<br>(mm) | Height<br>(mm) | Pizza/Carton |
|-----------|----------------|---------------|----------------|--------------|
| 13"       | 386            | 280           | 370            | 5            |

## 单击下面可查看定价,库存,交付和生命周期等信息

>>SGMICRO(圣邦微电子)